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Inclosure Material:

Glass all semiconductor device diode

Overall Length:

0.175 inches all semiconductor device diode

Terminal Length:

0.500 inches all semiconductor device diode

Overall Diameter:

0.075 inches all semiconductor device diode

Function For Which Designed:

Voltage variable capacitor

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-35 all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

12 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Features Provided:

Burn in and hermetically sealed case

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

28.0 reverse voltage, instantaneous all semiconductor device diode

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current preset all semiconductor device diode

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode

Capacitance Rating In Picofarads:

5.0 all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

125.0 degrees celsius junction all semiconductor device diode

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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